



# Dual-Input Smart Push-Button Reset IC

#### **Features**

- Operating Range: 1.6V~5.5V
- Supply Current in standby: < 1µA (V<sub>DD</sub> = 4V)
- Output Delay time (RST0 & 1 input pin): 10s Typ.
- Reset Pulse Time (SRO, nSRO Output): 400ms Typ.
- ESD Protection
  - ► Human Body Model: 2kV
  - ► Charged Device Model: 1.5kV
- Over-Temperature Protection
- -40°C to +85°C Temperature Range

### **Applications**

- Mobile Phones & Tablets
- Wearable Devices
- Portable Instruments
- Remote Controls
- Gaming
- DSC, DVR, GPS

### **Brief Description**

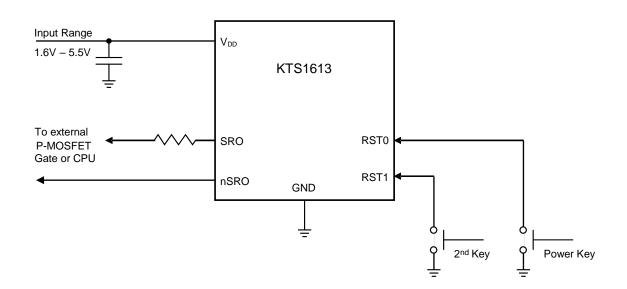
The KTS1613 is a two input, two output Smart Push-Button Reset IC. A reset pulse is generated for a fixed discharge time (400ms typ) after both manual reset inputs have been held low for the reset request time of 10s.

The KTS1613 operates over the 1.6 V to 5.5V supply voltage range, consuming less than 10 $\mu$ A of supply current at 4V.

The KTS1613 has 2 digital output pins, nSRO and SRO. nSRO is an active-low open-drain output pin. SRO is an active-high push-pull output which can be used to control a P-channel MOSFET battery disconnect switch. It features a soft turn on and turn off feature to reduce VBAT rising and falling overshoot.

The KTS1613 is available in lead-free, fully green compliant, small 10-pin UQFN 2.0mm x 1.5mm package.

## **Typical Application**

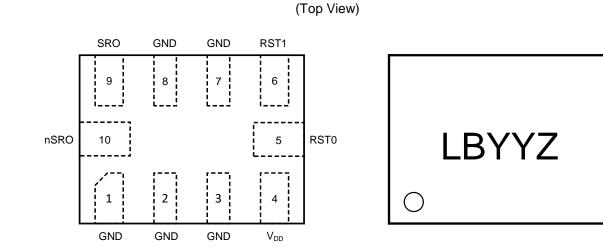




### **Pin Descriptions**

Pin #	Name	Function IO Characteri	
1, 2, 3, 7, 8	GND	Ground connection.	-
4	V <sub>DD</sub>	Power supply input.	-
5	RST0	Reset signal input 0.	Internal pull down (8MΩ)
6	RST1	Reset signal input 1.	No internal pull up resistor
9	SRO	Digital output. Active HIGH (VDD)	Push-Pull
10	nSRO	Digital output, Active LOW	Open-drain

UQFN2.0x1.5-10



10-Lead 2.0mm x 1.50mm x 0.55mm UQFN Package

Top Mark LB = Device ID Code, YY = Date Code, Z = Assembly Code



## Absolute Maximum Ratings<sup>1</sup>

(T <sub>A</sub> = 25°C unless	otherwise	noted)
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Symbol Description		Value	Units
V <sub>DD</sub>	Power supply input.	-0.3 to +12 (DC)	V
RST0, RST1, SRO, nSRO Reset inputs, Digital outputs.		-0.3 to +6	V
TJ	Maximum Junction Temperature Range	-40 to 150	
Ts	Storage Temperature Range	-65 to 150	°C
TLEAD	Maximum Soldering Temperature (at leads, 10sec)	300	

## **Thermal Capabilities**<sup>2</sup>

Symbol	Description	Value	Units
θја	Thermal Resistance – Junction to Ambient	73	°C/W
PD	Maximum Power Dissipation at T <sub>A</sub> ≤ 25°C	1712	mW
ΔP <sub>D</sub> /°C	Derating Factor Above $T_A = 25^{\circ}C$	13.7	mW/°C

### **Ordering Information**

Part Number	per Marking <sup>3</sup> Operating Temperatu		Package		
KTS1613EQU-TR	LBYYZ	-40°C to +85°C	UQFN2.0x1.5-10		

### **Recommended Operating Range<sup>4</sup>**

Description	Value		
V <sub>DD</sub>	-0.3V to 5.5V		
RST0, RST1 SRO, nSRO	-0.3V to 5V		

<sup>1.</sup> Stresses above those listed in Absolute Maximum Ratings may cause permanent damage to the device. Functional operation at conditions other than the operating conditions specified is not implied. Only one Absolute Maximum rating should be applied at any one time.

<sup>2.</sup> Junction to Ambient thermal resistance is highly dependent on PCB layout. Values are based on thermal properties of the device when soldered to a PCB board.

<sup>3. &</sup>quot;LBYYZ" is the device code, date code and assembly code respectively.

<sup>4.</sup> The device is not guaranteed to function outside of recommended operating condition.



### **Electrical Characteristics**<sup>5</sup>

The *Min* and *Max* specs are applied over the full operation temperature range of -40°C to +85°C,  $V_{IN} = 1.6V$  to 5.5V unless otherwise noted, while *Typ* values are specified at  $V_{DD} = 4.0V$  and room temperature (T<sub>A</sub> = 25°C) unless otherwise noted.

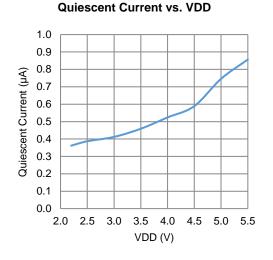
Symbol	Description	Conditions	Min	Тур	Max	Units
Basic Opera	tion					
V <sub>DD</sub>	Input Voltage Range		1.6		5.5	V
lq	Quiescent supply current	Standby (Exclude pull up/down resistor, Internal oscillator is off, V <sub>DD</sub> = 4V)			1	μA
Iss	Operation current	Active (Before reset signal output, Internal oscillator is on, V <sub>DD</sub> = 4V)			10	μA
Digital IO						
VIL	Digital input logic low level	RST0, RST1 pins			0.4	V
Vih	Digital input logic high level	$V_{DD} = 2.5V$ to $4.6V$	1.0			V
Vol	Digital output logic low level	SRO pin, I = 1.2µA (V <sub>DD</sub> = 4V)			0.3	V
Vон	Digital output logic high level		0.85*V <sub>DD</sub>	Vdd		V
١L	RST0/RST1 input leakage current		-	-	1	μA
Vol	Digital output logic low level	nSRO, lo = 2mA			0.3	V
RESET						
T <sub>R</sub>	Reset request time	$V_{DD} = 4V$	8.5	10	11.5	S
TD	Reset pulse time			400		ms
ESD PROTE	CTION					
	Human Body Model (HBM)	All pins		±2		kV
Vesd	IEC61000-4-2 Contact discharge	V <sub>DD</sub> pin		±8		kV
	IEC61000-4-2 Air gap discharge	V <sub>DD</sub> pin		±15		kV

<sup>5.</sup> All specifications are 100% production tested at  $T_A = +25$ °C, unless otherwise noted. Specifications are over -40°C to +85°C and are guaranteed by design.

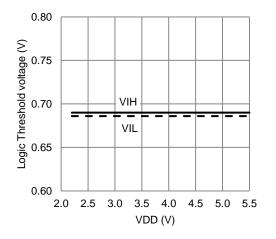


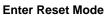
### **Typical Characteristics**

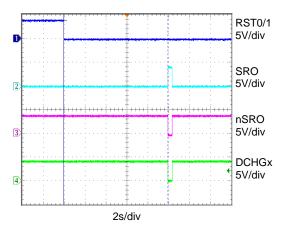
 $V_{DD} = 4V$ ,  $T_A = 25^{\circ}C$  unless otherwise specified.



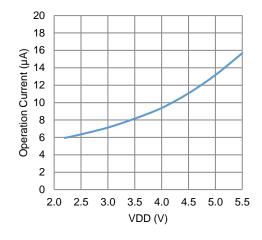
#### RST0/RST1 Digital Input Logic Threshold Vs. VDD



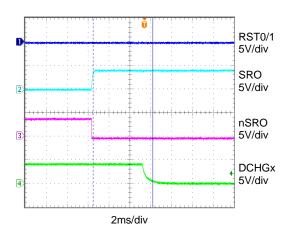




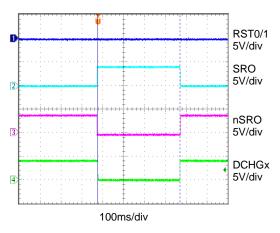
#### Operation Current vs. VDD (before Reset pulse)



Reset Mode Trigger







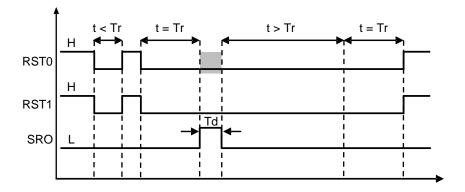


#### **Function Description**

#### Reset Timing

Reset occurs only after both RST0 and RST1 stay low for Tr duration, SRO output goes high for Td = 400ms, then SRO output goes low.

If RST0 & RST1 stay low indefinitely, KTS1613 only resets one time.

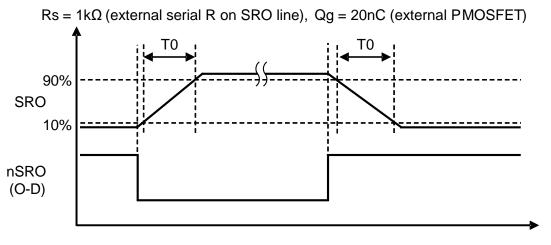


#### Figure 1. Reset Timing

#### Soft Turn ON and OFF

SRO output has soft turn on and turn off feature in order to reduce VBAT rising and falling overshoot. The output rising and falling time equal to 2ms typical.

nSRO is an open-drain output pin, there is no soft turn on & off feature for nSRO. The timing of SRO and nSRO is shown in Figure 4.







KTS1613

## **Functional Block Diagram**

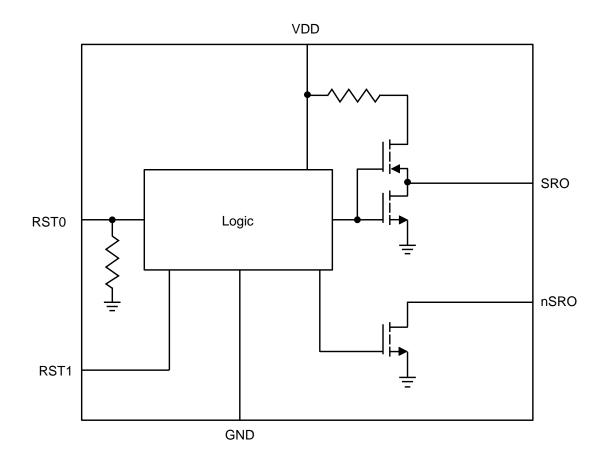


Figure 3. Block Diagram



## **Application Circuit**

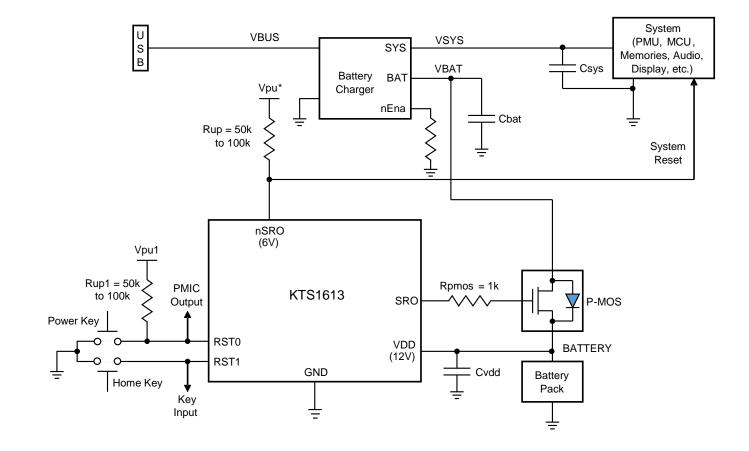


Figure 4. Application Circuit